



40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C
	13.7mΩ @ V _{GS} = 10V	49.8A
40V	26mΩ @ V _{GS} = 4.5V	36.7A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters

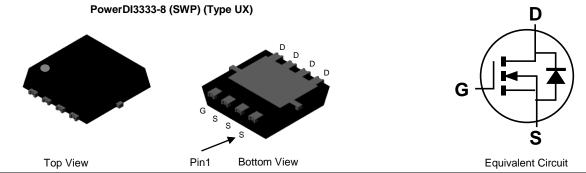
Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Low R_{DS(ON)} Ensures On State Losses are Minimized
- Excellent Qgd X RDS (ON) Product (FOM)
- Wettable Flank for Improved Optical Inspection
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4014LFVWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH4014LFVWQ-7	PowerDI3333-8 (SWP) (Type UX)	2,000/Tape & Reel
DMTH4014LFVWQ-13	PowerDI3333-8 (SWP) (Type UX)	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



PowerDI3333-8 (SWP) (Type UX)

 $\frac{H4W}{YY} = Product Type Marking Code$ $\frac{YY}{YW} = Date Code Marking$ $\frac{YY}{Y} = Last Two Digits of Year (ex: 20 = 2020)$ WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

^{2.} See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

^{3.} Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 6), V _{GS} = 10V	Tc = +25°C Tc = +100°C	ID	49.8 35.2	А
Continuous Drain Current (Note 5), VGS = 10V	T _A = +25°C T _A = +100°C	lo	11.5 8.1	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Iрм	180	А
Maximum Continuous Body Diode Forward Current (Note 6)		ls	45	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycl	e = 1%)	Ism	180	А
Avalanche Current, L = 0.1mH		las	19.8	А
Avalanche Energy, L = 0.1mH		E _{AS}	19.6	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.1	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{0JA}	48.6	°C/W
Total Power Dissipation (Note 6) T _C = +25°C		PD	57.7	W
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	2.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		-	1	μA	V _{DS} = 32V, V _{GS} = 0V	
Gate-Source Leakage	IGSS	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	1	—	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	9.8	13.7	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	RDS(ON)	—	14.5	26	11175	Vgs = 4.5V, ID = 10A	
Diode Forward Voltage	Vsd	—	0.9	1.2	V	V _{GS} = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	750	—		V _{DS} = 20V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss		225	_	pF		
Reverse Transfer Capacitance	Crss		21	_			
Gate Resistance	Rg	_	1.1		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	5.7				
Total Gate Charge (V _{GS} = 10V)	Qg	_	11.2		nC	$V_{DS} = 20V, I_D = 20A$	
Gate-Source Charge	Qgs	_	2.0		nc		
Gate-Drain Charge	Q _{gd}	—	2.2	_			
Turn-On Delay Time	t _{D(ON)}	—	3.5	—			
Turn-On Rise Time	tR	_	4.6			$V_{DD} = 20V, V_{GS} = 10V,$ $R_g = 1.6\Omega, I_D = 20A$	
Turn-Off Delay Time	tD(OFF)	_	12.4	—	ns		
Turn-Off Fall Time	tF	—	4.9	—	1		
Body Diode Reverse Recovery Time	trr		11.3		ns		
Body Diode Reverse Recovery Charge	Q _{RR}	—	9.5	—	nC	IF = 15A, di/dt = 400A/µs	

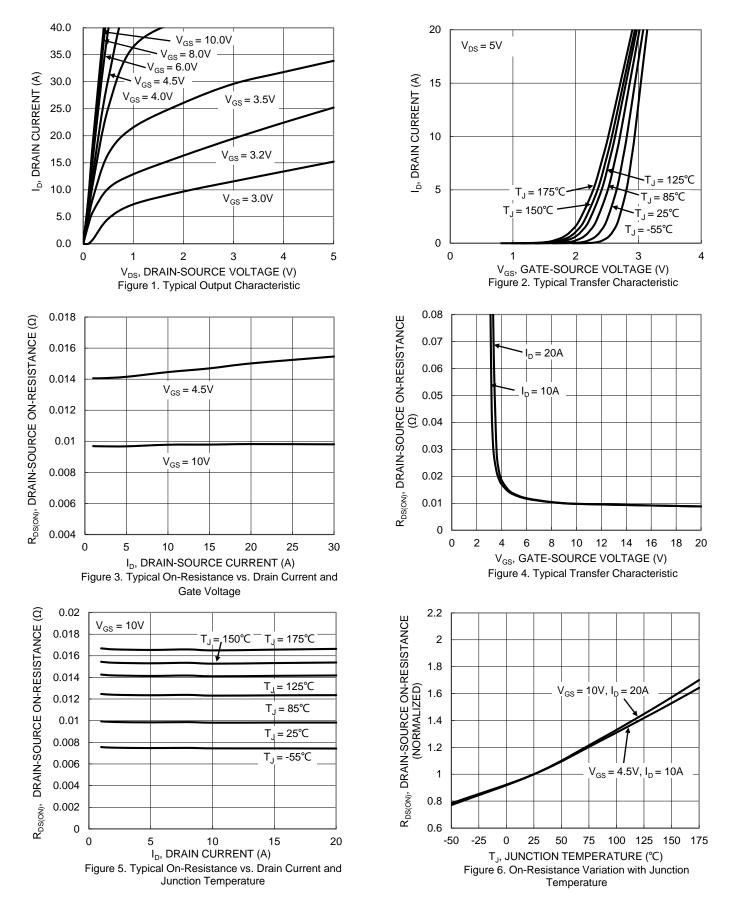
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

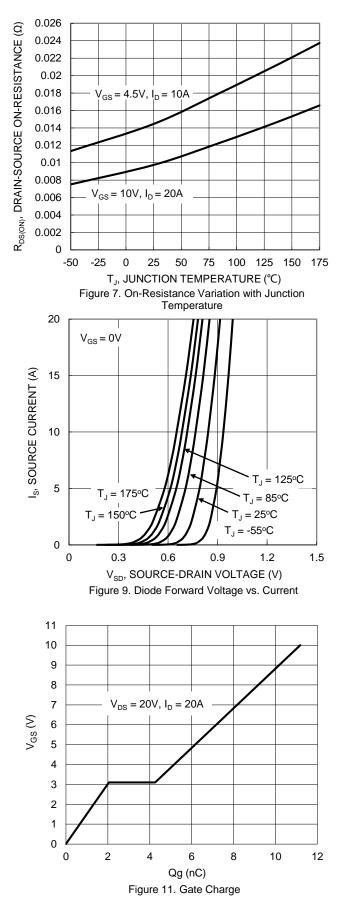


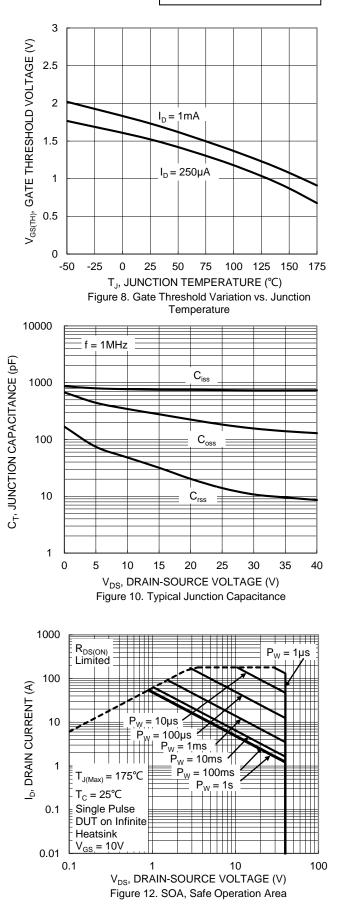
DMTH4014LFVWQ



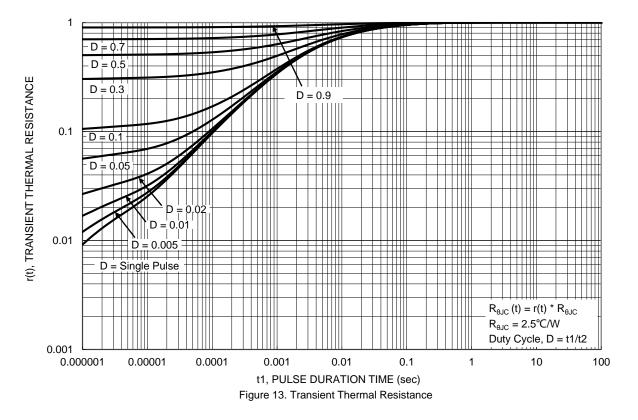


DMTH4014LFVWQ





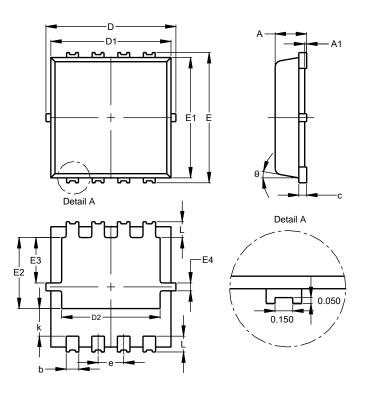






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



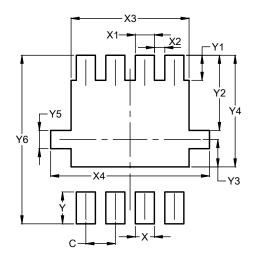
PowerDI3333-8 (SWP) (Type UX)

PowerDI3333-8 (SWP)						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
E	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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